

**E i n l a d u n g z u m G D C h - K o l l o q u i u m**  
**Am Freitag, den 03. Juli 2015 um 14:00 Uhr** spricht

**Herr Prof. Dr. G. Jeffrey Snyder**

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zum Thema: **COMPLEX THERMOELECTRIC MATERIALS**

The widespread use of thermoelectric generators has been limited by the low material efficiency of the thermoelectric material. A number of strategies for *Complex Thermoelectric Materials* [1] with higher thermoelectric figure of merit,  $zT$ , are being actively studied. Complex electronic band structures provide mechanisms to achieve high  $zT$  in thermoelectric materials through *band structure engineering*. High  $zT$  is obtained p-type PbTe and PbSe which contains both light and heavy valence bands that can be engineered by alloying to achieve high valley degeneracy which leads to an extraordinary peak  $zT$  of about 2 at 750K [2].

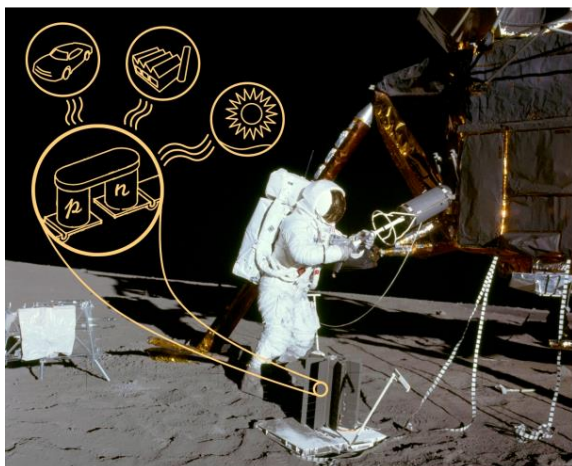


Figure: A thermoelectric generator directly converts heat into electricity with no moving parts. The long term reliability of these systems has encouraged NASA to use thermoelectric generators in many space probes since the 1960s (up to 35 years unattended). Today, thermoelectrics are being considered for terrestrial applications such as automotive and industrial waste heat recovery as well as solar-electricity generation.

Complex crystal structures that enable relatively low thermal conductivity have led to several new classes of thermoelectric materials.  $\text{Ca}_3\text{AlSb}_3$ ,  $\text{Ca}_5\text{Al}_2\text{Sb}_6$  and  $\text{Yb}_{14}\text{AlSb}_{11}$  are complex Zintl compounds containing differently connected  $\text{AlSb}_4$  tetrahedra that obtain  $zT$  near 1 at high temperatures. Fast diffusing or 'liquid-like' elements in the complex materials  $\text{Zn}_4\text{Sb}_3$  [3] and  $\text{Cu}_2\text{Se}$  [4] provide additional mechanisms to scatter and otherwise inhibit phonon heat conductivity. The principles of Zintl chemistry facilitates the search for new complex materials and the tuning of known thermoelectric materials with earth abundant, non-toxic elements [5]

Finally, the incorporation of nanometer sized microstructure reduces thermal conductivity from long mean-free-path phonons. This principle has been successfully demonstrated in  $(\text{Bi,Sb})_2\text{Te}_3$  alloys with arrays of dislocations at grain boundaries [6]. The synthesis of nanoscale composites can be controlled with the

aid of equilibrium phase diagrams (experimental or theoretically determined) to produce microstructure of varying composition and length scale [7].

[1] G. J. Snyder, E. S. Toberer. "Complex thermoelectric materials" *Nature Materials* 7, p 105 - 114 (2008); [2] Y. Z. Pei, G. J. Snyder, et al. "Convergence of Electronic Bands for High Performance Bulk Thermoelectrics" *Nature* 473, p 66 (2011); *Advanced Materials* 23, 5674 (2011); [3] H. Liu, X. Shi, G. J. Snyder, et al. "Liquid-like Copper Ion Thermoelectric Materials" *Nature Materials*, 11, 422 (2012); *APL Materials*, 1, 052107 (2013); [4] G. J. Snyder, et al., "Disordered Zinc in  $\text{Zn}_4\text{Sb}_3$  with Phonon Glass, Electron Crystal Thermoelectric Properties" *Nature Materials*, Vol 3, p. 458 (2004); *J. Mater. Chem.*, 20, 9877 (2010); [5] E. S. Toberer, A. F. May, G. J. Snyder, "Zintl Chemistry for Designing High Efficiency Thermoelectric Materials" *Chemistry of Materials* 22, p 624 (2010); [6] S. I. Kim, H. S. Kim, G. J. Snyder, S. W. Kim et al. "Dense dislocation arrays embedded in grain boundaries for high-performance bulk thermoelectrics" *Science*, 348, 6230 (2015); [7] Nicholas A. Heinz, T. Ikeda, Y. Pei and G. J. Snyder "Applying quantitative microstructure control in advanced functional composites" *Advanced Functional Materials* 24, 2135 (2014)

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**Alle Interessenten sind zu diesem Vortrag herzlich eingeladen.**

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 GDCh-Ortsverband

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 Dekan

Die Professoren des IMKM

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